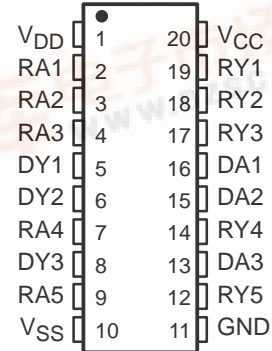


## LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU Recommendation V.28
- Single Chip With Easy Interface Between UART and Serial-Port Connector
- Less Than 9-mW Power Consumption
- Wide Driver Supply Voltage . . . 4.5 V to 13.2 V
- Driver Output Slew Rate Limited to 30 V/μs Max
- Receiver Input Hysteresis . . . 1100 mV Typ
- Push-Pull Receiver Outputs
- On-Chip Receiver 1-μs Noise Filter
- Functionally Interchangeable With Texas Instruments SN75185
- Operates Up to 120 kbit/s Over a 3-Meter Cable (See *Application Information* for Conditions)

DW OR N PACKAGE  
(TOP VIEW)



### description

The SN75C185 is a low-power BiMOS device containing three independent drivers and five receivers that are used to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE). Typically, the SN75C185 replaces one SN75188 and two SN75189 devices. This device conforms to TIA/EIA-232-F. The drivers and receivers of the SN75C185 are similar to those of the SN75C188 and SN75C189A, respectively. The drivers have a controlled output slew rate that is limited to a maximum of 30 V/μs, and the receivers have filters that reject input noise pulses that are shorter than 1 μs. Both these features eliminate the need for external components.

The SN75C185 uses the low-power BiMOS technology. In most applications, the receivers contained in this device interface to single inputs of peripheral devices such as ACEs, UARTS, or microprocessors. By using sampling, such peripheral devices usually are insensitive to the transition times of the input signals. If this is not the case, or for other uses, it is recommended that the SN75C185 receiver outputs be buffered by single Schmitt input gates or single gates of the HCMOS, ALS, or 74F logic families.

The SN75C185 is characterized for operation from 0°C to 70°C.

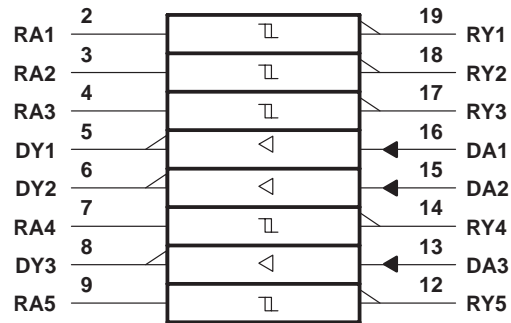
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

# SN75C185

## LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

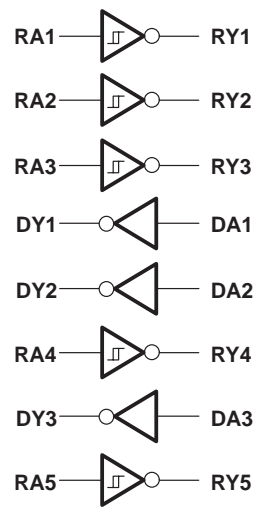
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logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

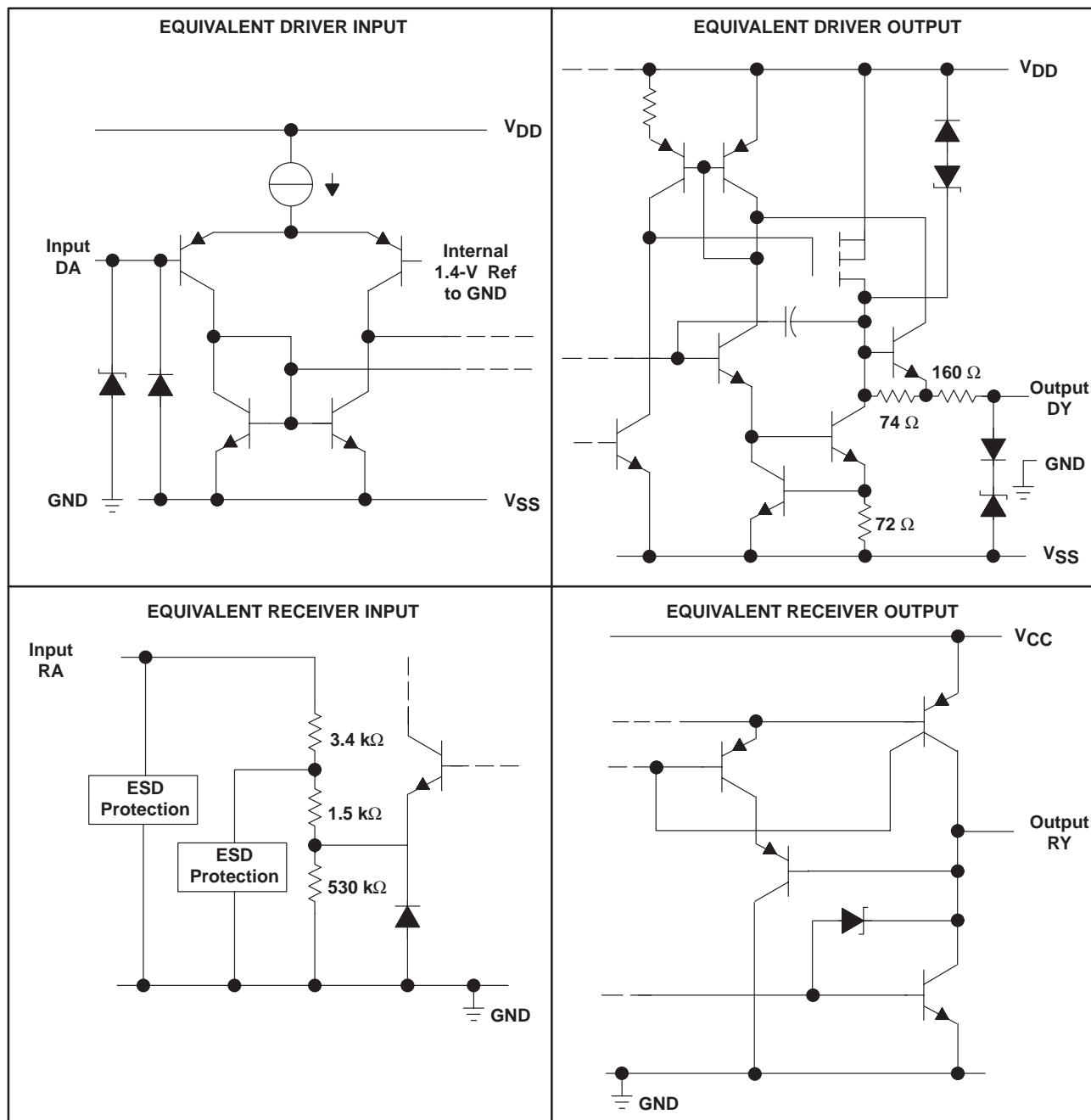
logic diagram (positive logic)



# SN75C185 LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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## equivalent schematics of inputs and outputs



All resistor values are nominal.

# SN75C185

## LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, $V_{DD}$ (see Note 1)	13.5 V
Supply voltage, $V_{SS}$	–13.5 V
Supply voltage, $V_{CC}$	7 V
Input voltage range, $V_I$ : Driver	$V_{SS}$ to $V_{DD}$
Receiver	–30 V to 30 V
Output voltage range, $V_O$ : Driver	$V_{SS} - 6$ V to $V_{DD} + 6$ V
Receiver	–0.3 V to $V_{CC} + 0.3$ V
Package thermal impedance, $\theta_{JA}$ (see Note 2): DW package	58°C/W
N package	69°C/W
Operating free-air temperature range, $T_A$	0°C to 70°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, $T_{stg}$	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to network GND.  
2. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage	$V_{DD}$	4.5	12	13.2	V
	$V_{SS}$	–4.5	–12	–13.2	V
	$V_{CC}$	4.5	5	6	V
$V_I$ Input voltage (see Note 3)	Drivers	$V_{SS} + 2$		$V_{DD}$	V
	Receivers	–25		25	
$V_{IH}$ High-level input voltage	Drivers	2			V
$V_{IL}$ Low-level input voltage				0.8	V
$I_{OH}$ High-level output current	Receivers			–1	mA
$I_{OL}$ High-level output current				3.2	mA
$T_A$ Operating free-air temperature		0		70	°C

NOTE 3: The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if –10 V is a maximum, the typical value is a more negative voltage.

### supply currents

PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
$I_{DD}$ Supply current from $V_{DD}$	No load, All inputs at 2 V or 0.8 V	$V_{DD} = 5$ V, $V_{SS} = -5$ V		115	200	$\mu$ A
		$V_{DD} = 12$ V, $V_{SS} = -12$ V		115	200	
$I_{SS}$ Supply current from $V_{SS}$	No load, All inputs at 2 V or 0.8 V	$V_{DD} = 5$ V, $V_{SS} = -5$ V	–115		–200	$\mu$ A
		$V_{DD} = 12$ V, $V_{SS} = -12$ V	–115		–200	
$I_{CC}$ Supply current from $V_{CC}$	No load All inputs at 0 or 5 V	$V_{DD} = 5$ V, $V_{SS} = -5$ V			750	$\mu$ A
		$V_{DD} = 12$ V, $V_{SS} = -12$ V			750	

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## LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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### DRIVER SECTION

**electrical characteristics over operating free-air temperature range,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$ ,  $V_{CC} = 5\text{ V} \pm 10\%$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{OH}$ High-level output voltage	$V_{IL} = 0.8\text{ V}$ , $R_L = 3\text{ k}\Omega$ , See Figure 1	$V_{DD} = 5\text{ V}$ , $V_{SS} = -5\text{ V}$ $V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$	4 10	4.5 10.8	V
$V_{OL}$ Low-level output voltage (see Note 3)	$V_{IH} = 0.8\text{ V}$ , $R_L = 3\text{ k}\Omega$ , See Figure 1	$V_{DD} = 5\text{ V}$ , $V_{SS} = -5\text{ V}$ $V_{DD} = 12\text{ V}$ , $V_{SS} = -12\text{ V}$	-4.4 -10.7	-4 -10	V
$I_{IH}$ High-level input current	$V_I = 5\text{ V}$ , See Figure 2			1	$\mu\text{A}$
$I_{IL}$ Low-level input current	$V_I = 0$ , See Figure 2			-1	$\mu\text{A}$
$I_{OS(H)}$ High-level short-circuit output current (see Note 4)	$V_I = 0.8\text{ V}$ , $V_O = 0$ or $V_O = V_{SS}$ , See Figure 1	-4.5	-12	-19.5	mA
$I_{OS(L)}$ Low-level short-circuit output current (see Note 4)	$V_I = 2\text{ V}$ , $V_O = 0$ or $V_O = V_{DD}$ , See Figure 1	4.5	12	19.5	mA
$r_o$ Output resistance	$V_{DD} = V_{SS} = V_{CC} = 0$ , $V_O = -2\text{ V}$ to $2\text{ V}$ , See Note 5	300	400		$\Omega$

† All typical values are at  $T_A = 25^\circ\text{C}$ .

- NOTES: 3. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if  $-10\text{ V}$  is a maximum, the typical value is a more negative voltage.
4. Not more than one output should be shorted at one time.
5. Test conditions are those specified by TIA/EIA-232-F.

**switching characteristics,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$ ,  $V_{CC} = 5\text{ V} \pm 10\%$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted) (see Figure 3)**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$ Propagation delay time, low- to high-level output (see Note 6)	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$		1.2	3	$\mu\text{s}$
$t_{PHL}$ Propagation delay time, high- to low-level output (see Note 6)			2.5	3.5	$\mu\text{s}$
$t_{TLH}$ Transition time, low- to high-level output		0.53	2	3.2	$\mu\text{s}$
$t_{THL}$ Transition time, high- to low-level output		0.53	2	3.2	$\mu\text{s}$
$t_{TLH}$ Transition time, low- to high-level output (see Note 7)	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 2500\text{ pF}$		1		$\mu\text{s}$
$t_{THL}$ Transition time, high- to low-level output (see Note 7)			1		$\mu\text{s}$
$S_R$ Output slew rate (see Note 7)	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 15\text{ pF}$	4	10	30	$\text{V}/\mu\text{s}$

- NOTES: 6.  $t_{PHL}$  and  $t_{PLH}$  include the additional time due to on-chip slew rate and are measured at the 50% points.
7. Measured between 3-V and  $-3\text{ V}$  points of output waveform (TIA/EIA-232-F conditions), and all unused inputs are tied either high or low.

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## LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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### RECEIVER SECTION

**electrical characteristics over operating free-air temperature range,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$ ,  $V_{CC} = 5\text{ V} \pm 10\%$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{IT+}$	Positive-going input threshold voltage	See Figure 5	1.6	2.1	2.55	V
$V_{IT-}$	Negative-going input threshold voltage	See Figure 5	0.65	1	1.25	V
$V_{hys}$	Input hysteresis voltage ( $V_{IT+} - V_{IT-}$ )		600	1100		mV
$V_{OH}$	High-level output voltage	$V_I = 0.75\text{ V}$ , $I_{OH} = -20\text{ }\mu\text{A}$ , See Figure 5 and Note 8	3.5			V
		$V_I = 0.75\text{ V}$ , $I_{OH} = -1\text{ mA}$ , See Figure 5, $V_{CC} = 4.5\text{ V}$	2.8	4.4		
		$V_I = 0.75\text{ V}$ , $I_{OH} = -1\text{ mA}$ , See Figure 5, $V_{CC} = 5\text{ V}$	3.8	4.9		
		$V_I = 0.75\text{ V}$ , $I_{OH} = -1\text{ mA}$ , See Figure 5, $V_{CC} = 5.5\text{ V}$	4.3	5.4		
$V_{OL}$	Low-level output voltage	$V_I = 3\text{ V}$ , $I_{OL} = 3.2\text{ mA}$ , See Figure 5		0.17	0.4	V
$I_{IH}$	High-level input current	$V_I = 3\text{ V}$	0.43	0.55	1	mA
		$V_I = 25\text{ V}$	3.6	4.6	8.3	
$I_{IL}$	Low-level input current	$V_I = -3\text{ V}$	-0.43	-0.55	-1	mA
		$V_I = -25\text{ V}$	-3.6	-5.0	-8.3	
$I_{OS(H)}$	Short-circuit output at high level	$V_I = 0.75\text{ V}$ , $V_O = 0$ , See Figure 4		-8	-15	mA
$I_{OS(L)}$	Short-circuit output at low level	$V_I = V_{CC}$ , $V_O = V_{CC}$ , See Figure 4		13	25	mA

† All typical values are at  $T_A = 25^\circ\text{C}$ .

NOTE 8: If the inputs are left unconnected, the receiver interprets this as an input low, and the receiver outputs remain in the high state.

**switching characteristics,  $V_{DD} = 12\text{ V}$ ,  $V_{SS} = -12\text{ V}$ ,  $V_{CC} = 5\text{ V} \pm 10\%$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted) (see Figure 6)**

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{PLH}$	Propagation delay time, low- to high-level output	$R_L = 5\text{ k}\Omega$ , $C_L = 50\text{ pF}$		3	4	$\mu\text{s}$
$t_{PHL}$	Propagation delay time, high- to low-level output			3	4	$\mu\text{s}$
$t_{TLH}$	Transition time, low- to high-level output			300	450	ns
$t_{THL}$	Transition time, high- to low-level output			100	300	ns
$t_{w(N)}$	Duration of longest pulse rejected as noise (see Note 9)	$R_L = 5\text{ k}\Omega$ , $C_L = 50\text{ pF}$	1		4	$\mu\text{s}$

NOTE 9: The receiver ignores any positive- or negative-going pulse that is less than the minimum value of  $t_{w(N)}$  and accepts any positive- or negative-going pulse greater than the maximum of  $t_{w(N)}$ .

# SN75C185 LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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## PARAMETER MEASUREMENT INFORMATION

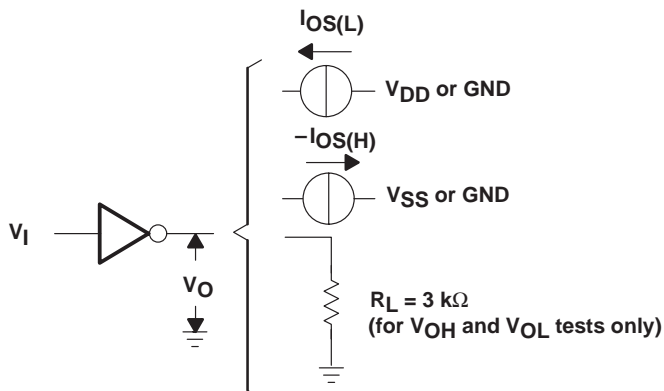


Figure 1. Driver Test Circuit for  $V_{OH}$ ,  $V_{OL}$ ,  $I_{OS(H)}$ , and  $I_{OS(L)}$

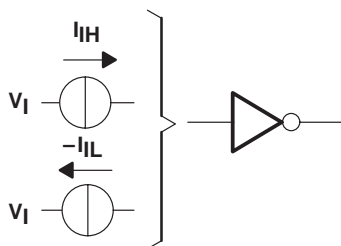
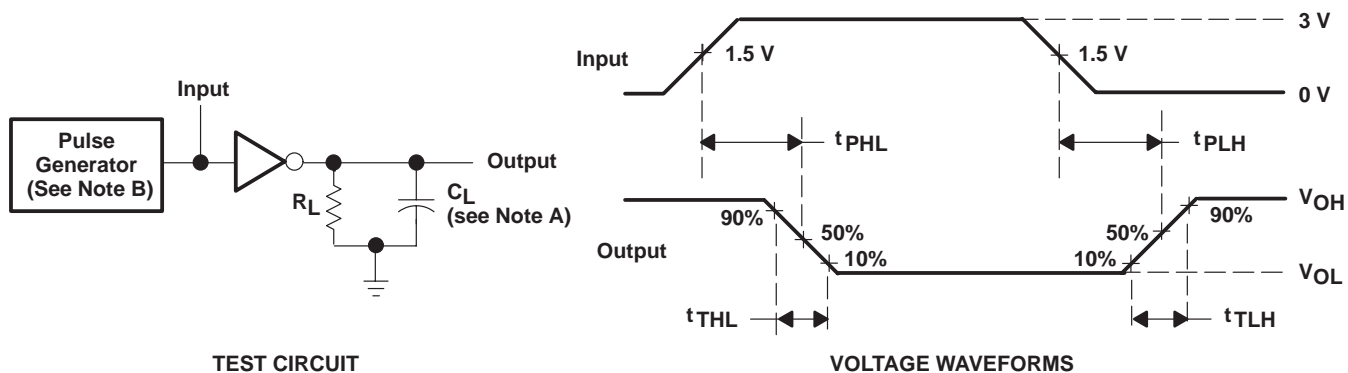


Figure 2. Driver Test Circuit for  $I_{IH}$  and  $I_{IL}$



NOTES: A.  $C_L$  includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $t_W = 25\text{ }\mu\text{s}$ ,  $\text{PRR} = 20\text{ kHz}$ ,  $Z_O = 50\text{ }\Omega$ ,  $t_r = t_f < 50\text{ ns}$ .

Figure 3. Driver Test Circuit and Voltage Waveforms

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## LOW-POWER MULTIPLE DRIVERS AND RECEIVERS

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### PARAMETER MEASUREMENT INFORMATION

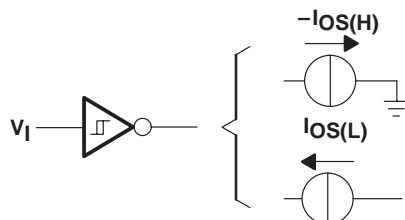


Figure 4. Receiver Test Circuit for  $I_{OS(H)}$  and  $I_{OS(L)}$

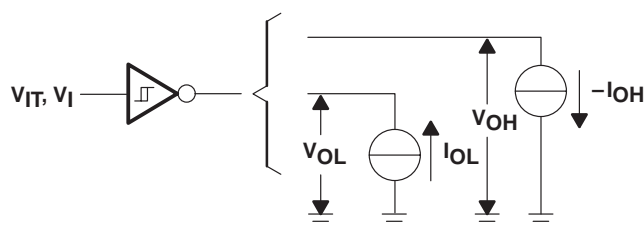
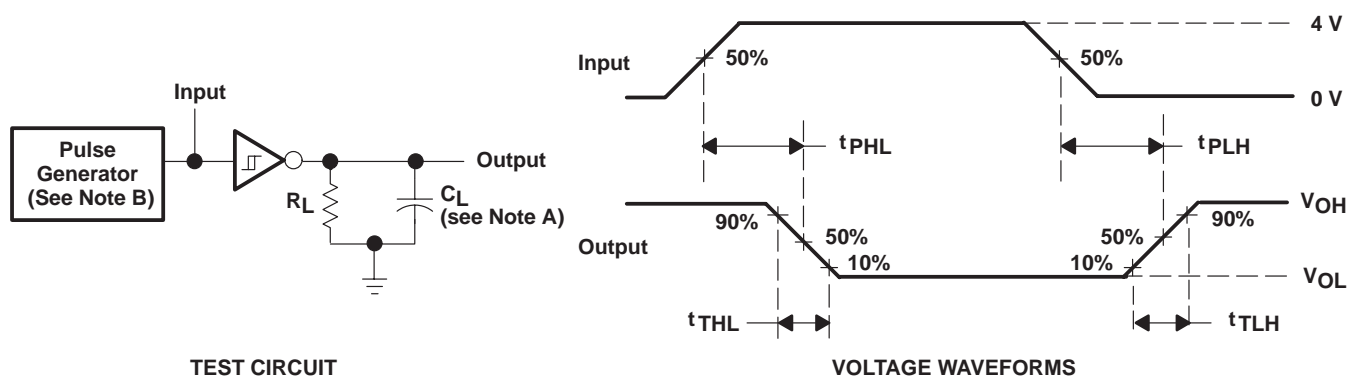


Figure 5. Receiver Test Circuit for  $V_{IT}$ ,  $V_{OH}$ , and  $V_{OL}$



NOTES: A.  $C_L$  includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $t_W = 25 \mu s$ ,  $PRR = 20 \text{ kHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r = t_f < 50 \text{ ns}$ .

Figure 6. Receiver Propagation and Transition Times



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## APPLICATION INFORMATION

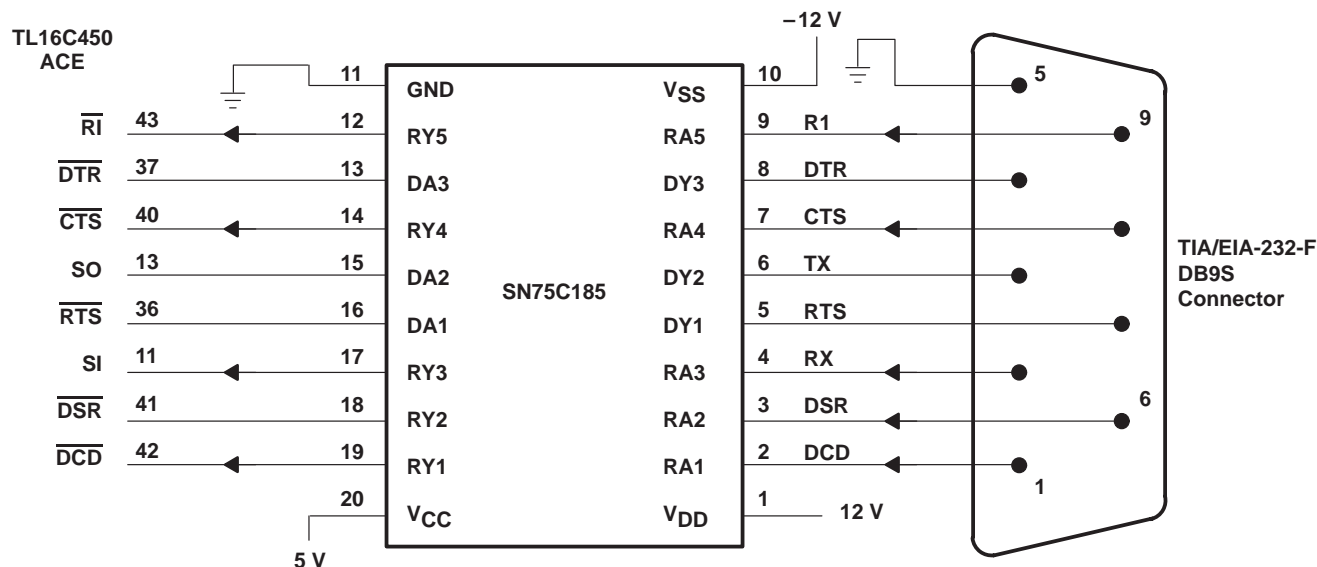
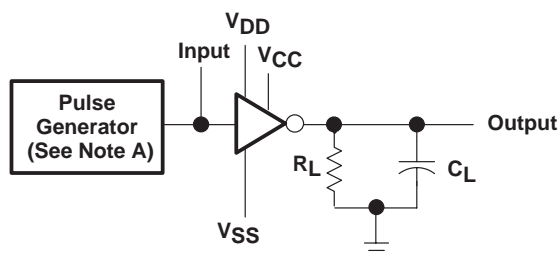


Figure 7. Typical Connection

The SN75C185 supports data rates up to 120 kbit/s over a 3-meter cable. Laboratory experiments show that, with  $C_L = 500$  pF and  $R_L = 3$  k $\Omega$  (minimum RS-232 input resistance load), the device can support this data rate. The 500-pF load approximates a typical 3-meter cable because the maximum RS-232 specification is 2500 pF (or about 15 meters). Figure 8 shows the test circuit used. Temperature was varied from 0°C to 70°C for the experiment.



- NOTES: A. The pulse generator has the following characteristics: PRR = 60 kHz (120 kbit/s),  $Z_O = 50$   $\Omega$ .  
B.  $V_{CC} = 5$  V,  $V_{DD} = 12$  V,  $V_{SS} = -12$  V.

Figure 8. Data-Rate Test Circuit

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